

Lecture 4

- Current in a Solid
 - Carrier (electron) Density
 - Conductivity
 - Ohm's Law
- Worked Example

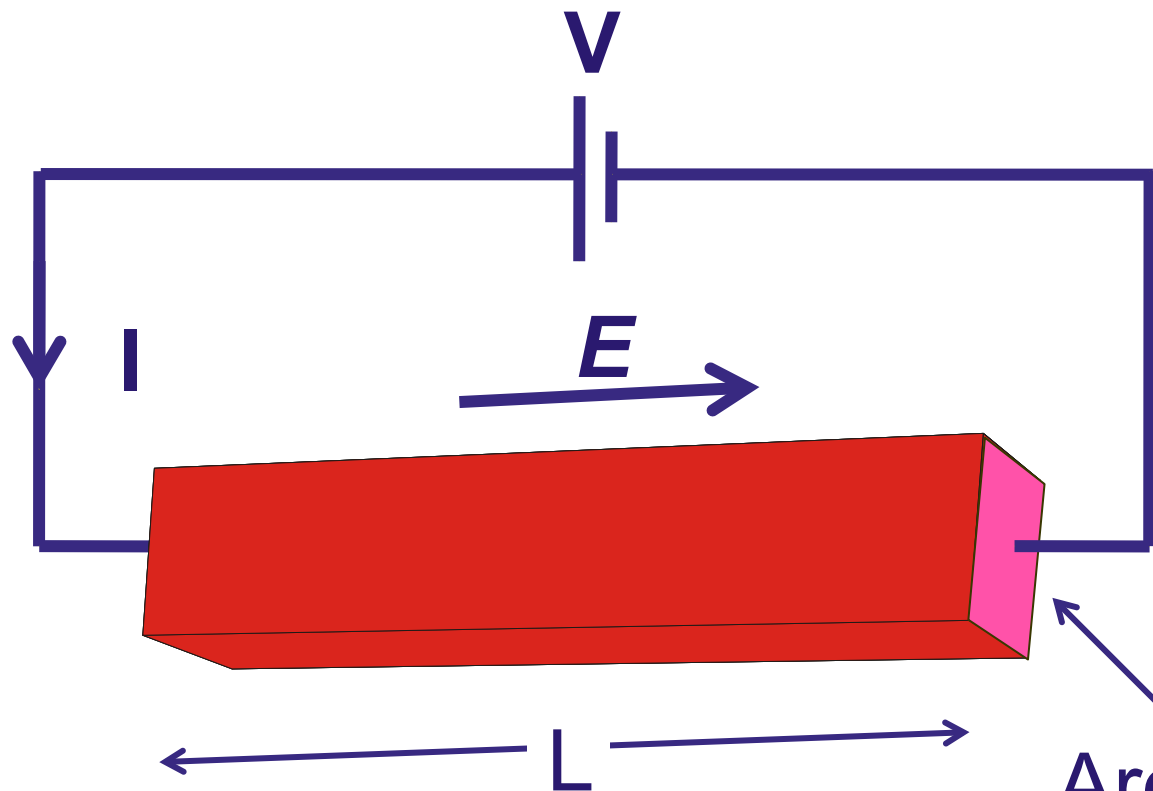
Current in a Solid

Three causes of current

1. An electric potential gradient dV/dx (i.e. an ***E***-field)
2. An electron density gradient dn/dx
3. A temperature gradient dT/dx

We will first look at 1 – applying a voltage difference or ***E***-field

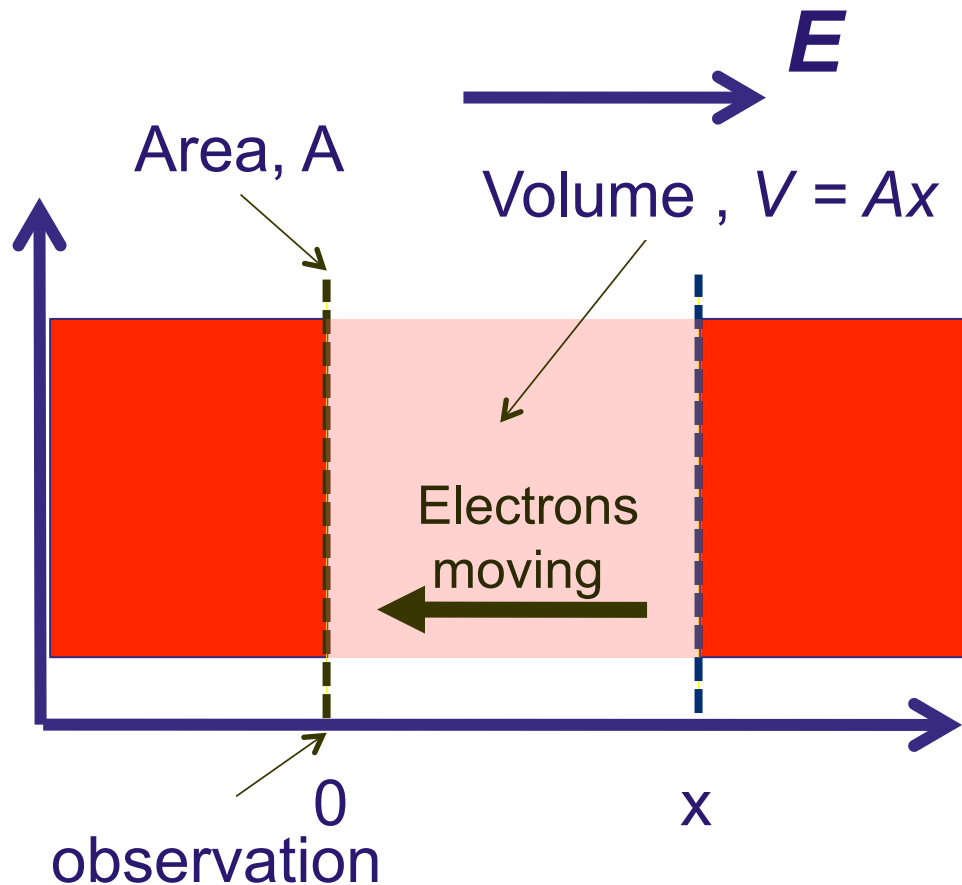
Solid with Free Electrons



- $E = V/L$
- Define a current density,
 $J = I/A \text{ (Am}^{-2}\text{)}$

Note the direction of E

Longitudinal Slice



Average drift velocity, \mathbf{v}_d , for electrons with density, $n \text{ m}^{-3}$.

In time t , all electrons in light coloured region will move past observation point

$$\rightarrow x = \mathbf{v}_d t$$

Number of electrons in this volume is

$$n V = n A x = n A v_d t$$

- Remember we are interested in Current.
- Definition of Current – charge flow per second.
- Charge on electron = $-e$ ($e = 1.6 \times 10^{-19}$ C) so in unit time (per second) the amount of charge flowing past our observation point is:

$$\text{current, } I = - n A e v_d$$

- The current density (current per unit area) is given by;

$$J = I/A = - n e v_d$$

- NOTE: J and I are both in opposite direction to electron flow
- Sometimes drift velocity written as just v
- Sometimes charge on electron written as e or q

Eliminate v_d

- The previous equation is only useful if we know the drift velocity (we generally don't), which we have derived as

$$v_d = -\mu E$$

- Giving the more useful form $J = ne\mu E$
- So the current density in our solid depends upon
 - Carrier concentration – i.e. how many electrons are there
 - E -field – magnitude of dV/dx
 - Mobility - how easy the carriers can move
 - The charge on an electron (fixed)

Ohm's Law

We can now derive a familiar and important equation:

$$J = ne\mu E \quad \text{can be simplified to} \quad J = \sigma E$$

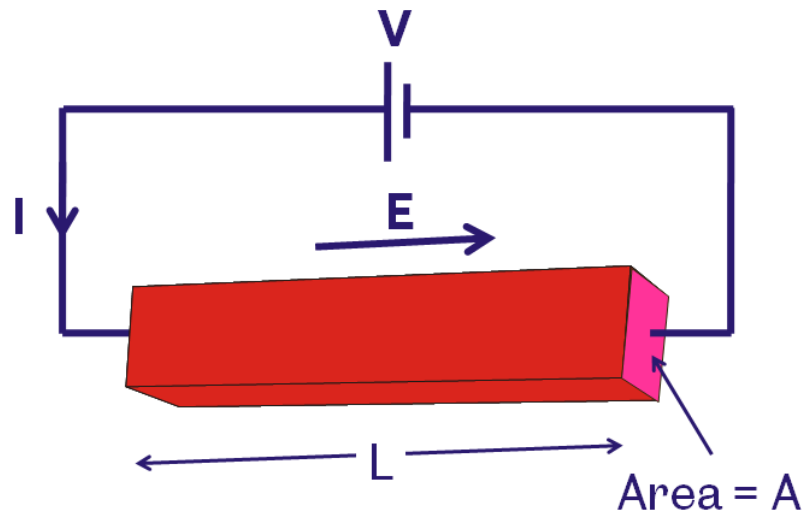
Where the conductivity $\sigma = ne\mu$

Conductivity is inverse of *resistivity* $\rho = \frac{1}{\sigma}$

This is the general form of Ohm's law $I = V/R$
(J becomes I , E becomes V , σ becomes $1/R$)



Ohm's Law (2)



$$J = \frac{I}{A}$$

$$E = \frac{V}{L}$$

$$J = \sigma E$$

combining

$$\frac{I}{A} = \frac{\sigma V}{L}$$

$$I = \frac{\sigma AV}{L}$$

This is just Ohm's law ($I = V/R$), hence

$$R = \frac{L}{\sigma A} = \rho L/A$$

i.e. R depends on **both** geometry and conductivity ($n e \mu$)

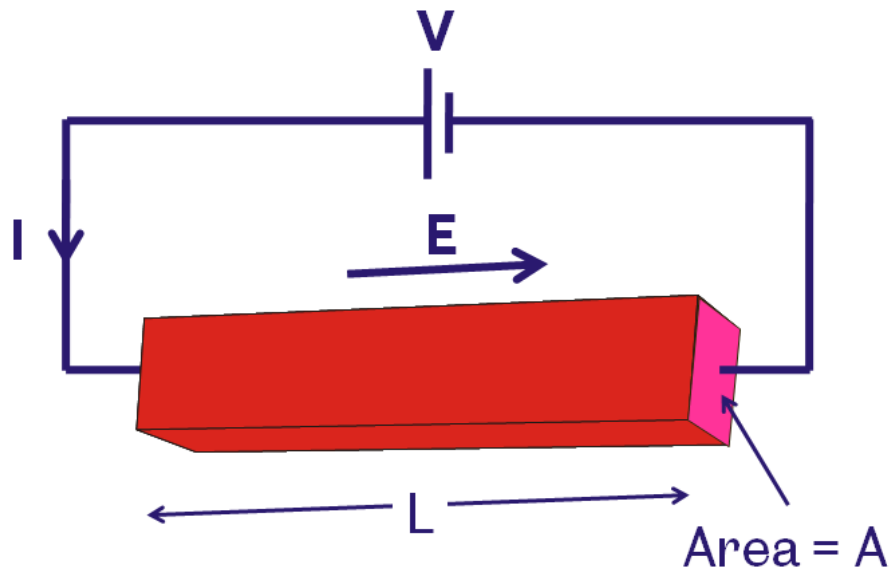
Drift Velocity Example

A 2cm long Si rod with cross sectional area of 5mm^2 has a voltage of 10V applied across its length, giving a current of 3 mA. The rod is known to have a uniform density of free electrons and temperature throughout its length.

- a) What is the average time between collisions in the material?
- b) What is the average drift velocity of the electrons in the rod?
- c) What is the concentration of the electrons in the material?

Given that $\mu = 1200 \text{ cm}^2\text{V}^{-1}\text{s}^{-1}$; $m^* = 0.98m_e$ ($m_e = 9.11 \times 10^{-31} \text{ Kg}$); $e = 1.6 \times 10^{-19} \text{ C}$

Visualization, Unit Conversion



$$L = 2 \times 10^{-2} \text{ m}$$

$$A = 5 \times 10^{-6} \text{ m}^2$$

$$V = 10 \text{ V}$$

$$I = 3 \times 10^{-3} \text{ A}$$

$$\mu = 0.12 \text{ m}^2 \text{V}^{-1} \text{s}^{-1}$$

$$m^* = 0.98 m_e$$

$$m_e = 9.11 \times 10^{-31} \text{ Kg}$$

a) Determine τ

Definition of mobility $\mu = \frac{e\tau}{m^*}$

Rearranging $\tau = \frac{\mu m^*}{e}$

$$\tau = \frac{0.12 \times 0.98 \times 9.11 \times 10^{-31}}{1.6 \times 10^{-19}} = 6.7 \times 10^{-13} \text{ s}$$

b) Determine v_d

Drift velocity and E-field related by $v_d = -\mu E$

E-field? 10V over 2cm length $E = \frac{V}{L} = \frac{10}{0.02} = 500 \text{ Vm}^{-1}$

Hence drift velocity, $v_d = -\mu E = -0.12 \times 500 = -60 \text{ ms}^{-1}$

c) Determine n

Current and voltage give value of resistance of rod

$$R = \frac{V}{I} = \frac{10}{3 \times 10^{-3}} = 3.3 \times 10^3 \Omega$$

Dimensions are known - can calculate the conductivity

$$R = \frac{L}{\sigma A} \quad \sigma = \frac{L}{RA} = \frac{0.02}{3.33 \times 10^3 \times 5 \times 10^{-6}} = 1.2 \Omega^{-1} \text{m}^{-1}$$

Know relation between conductivity and carrier density

$$n = \frac{\sigma}{e\mu} = \frac{1.2}{1.6 \times 10^{-19} \times 0.12} = 6.25 \times 10^{19} \text{ m}^{-3}$$

Summary

- Current density is current per unit area flowing in a material
- Current density is increased with increasing carrier density, increased mobility, and increased ***E***-field.
- Conductivity is the reciprocal of resistivity
- The current density is the product of the ***E***-field and conductivity of the material